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November 2013

SGS10N60RUFD 600 V, 10 A Short Circuit Rated IGBT

General Description

Fairchild's RUFD series of Insulated Gate Bipolar Transistors (IGBTs) provide low conduction and switching losses as well as short circuit ruggedness. The RUFD series is designed for applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short circuit ruggedness is a required feature.

Features

- 10 A, 600 V, T_C = 100°C
- Low Saturation Voltage: V_{CE}(sat) = 2.2 V @ I_C = 10 A
- High Speed Switching
- High Input Impedance
- · Short Circuit Rating

Applications

Motor Control, UPS, General Inverter





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		SGS10N60RUFD	Unit
V _{CES}	Collector-Emitter Voltage		600	V
V _{GES}	Gate-Emitter Voltage		± 20	V
	Collector Current	@ $T_C = 25^{\circ}C$	16	Α
I _C	Collector Current	@ T _C = 100°C	10	Α
I _{CM (1)}	Pulsed Collector Current	30	Α	
	Diode Continuous Forward Current	@ T _C = 25°C	24	Α
l _F	Diode Continuous Forward Current	@ T _C = 100°C	12	Α
I _{FM}	Diode Maximum Forward Current		92	Α
	Short Circuit Withstand Time	@ T _C = 100°C	10	μS
$\frac{T_{SC}}{P_{D}}$	Maximum Power Dissipation	@ $T_C = 25^{\circ}C$	55	W
	Maximum Power Dissipation	@ T _C = 100°C	22	W
T _J	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temp. for soldering purposes, 1/8" from case for 5 second	300	°C	

Notes:
(1) Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
R _{θJC} (IGBT)	Thermal Resistance, Junction-to-Case		2.3	°C/W
$R_{\theta JC}(DIODE)$	Thermal Resistance, Junction-to-Case		3.7	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		62.5	°C/W

Symbol	Parameter	Test Conditions		Тур.	Max.	Unit
Off Chai	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V}, I_{C} = 250 \text{ uA}$	600			V
$\Delta B_{VCES}/$ $\Delta T_{.I}$	Temperature Coeff. of Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA		0.6		V/°C
I _{CES}	Collector Cut-off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$			250	μΑ
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$			± 100	nA
On Char	racteristics					
$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 10 \text{ mA}, V_{CE} = V_{GE}$	5.0	6.0	8.5	٧
Vor	Collector to Emitter	$I_C = 10 \text{ A}, V_{GE} = 15 \text{ V}$		2.2	2.8	V
V _{CE(sat)}	Saturation Voltage	$I_C = 16 \text{ A}, V_{GE} = 15 \text{ V}$		2.5		V
Dynami	Characteristics					
C _{ies}	Input Capacitance	V 20 V V 01 V		660		pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz		115		pF
C _{res}	Reverse Transfer Capacitance			25		pF
t _{d(on)}	Turn-On Delay Time			15		ns
t _r	Rise Time	$V_{CC} = 300 \text{ V, } I_{C} = 10 \text{ A,}$		30		ns
t _{d(off)}	Turn-Off Delay Time			36	50	nS
t _f	Fall Time	$R_G = 20 \Omega, V_{GE} = 15 V,$		158	200	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C		141		μJ
E _{off}	Turn-Off Switching Loss			215		μJ
E _{ts}	Total Switching Loss			356	500	μJ
t _{d(on)}	Turn-On Delay Time			16		ns
t _r	Rise Time			33		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, I_{C} = 10 \text{ A},$		42	60	ns
t _f	Fall Time	$R_G = 20 \Omega, V_{GE} = 15 V,$	/	242	350	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C		161		μJ
E _{off}	Turn-Off Switching Loss			452		μJ
E _{ts}	Total Switching Loss			613	860	μJ
T _{sc}	Short Circuit Withstand Time	$V_{CC} = 300 \text{ V}, V_{GE} = 15 \text{ V}$ @ $T_C = 100^{\circ}\text{C}$	10			μS
Q_g	Total Gate Charge	$V_{CE} = 300 \text{ V}, I_{C} = 10 \text{ A},$		30	45	nC
Q _{ge}	Gate-Emitter Charge	$V_{GF} = 15 \text{ V}$		5	10	nC
Q_{gc}	Gate-Collector Charge	0_		8	16	nC
Le	Internal Emitter Inductance	Measured 5mm from PKG		7.5		nH

Electrical Characteristics of DIODE $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V _{FM}	Diode Forward Voltage	I _F = 12 A	$T_C = 25^{\circ}C$		1.4	1.7	1.7 V
		1F = 12 A	T _C = 100°C	-	1.3		
t _{rr} Diode Rever	Diode Reverse Recovery Time		$T_C = 25^{\circ}C$		42	60	nc
	Diode Reverse Recovery Time		T _C = 100°C		60		ns
1	I _{rr} Diode Peak Reverse Recovery Current	I _F = 12 A,	$T_C = 25^{\circ}C$		3.5	6.0	Α
'rr		$di_F/dt = 200 A/\mu s$	T _C = 100°C	-	5.6		
Q _{rr}	Diode Reverse Recovery Charge		$T_C = 25^{\circ}C$		80	180	nC
			$T_C = 100$ °C	-	220		

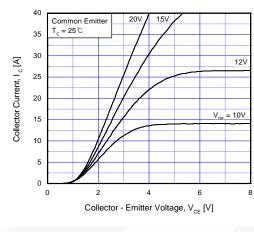


Fig 1. Typical Output Chacracteristics

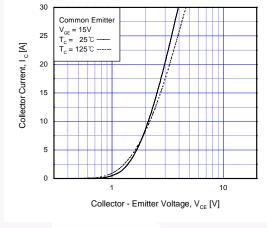


Fig 2. Typical Saturation Voltage Characteristics

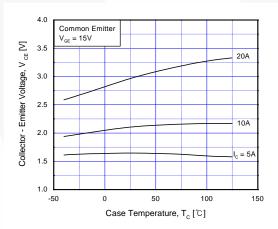


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

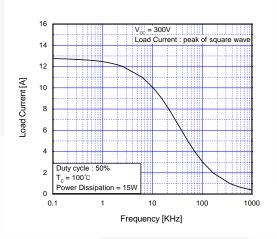


Fig 4. Load Current vs. Frequency

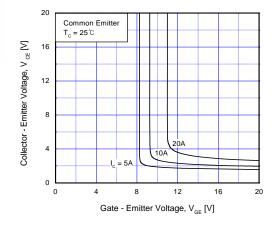


Fig 5. Saturation Voltage vs. V_{GE}

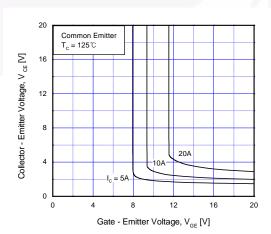
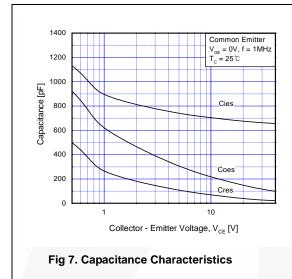
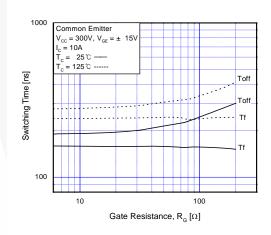


Fig 6. Saturation Voltage vs. $V_{\rm GE}$



Common Emitter $V_{\rm CC}=300V, V_{\rm CE}=\pm 15V$ $I_{\rm C}=10A$ $I_{\rm C}=25\,{\rm C}$ $I_{\rm C}=125\,{\rm C}$ I_{\rm

Fig 8. Turn-On Characteristics vs.
Gate Resistance



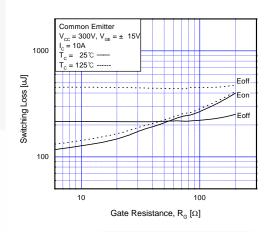
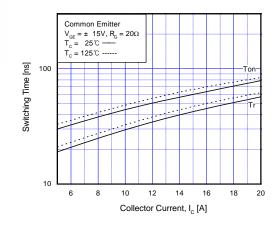


Fig 9. Turn-Off Characteristics vs.
Gate Resistance

Fig 10. Switching Loss vs. Gate Resistance



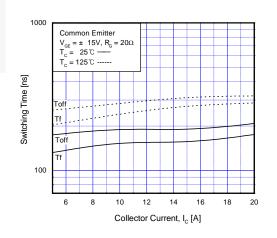
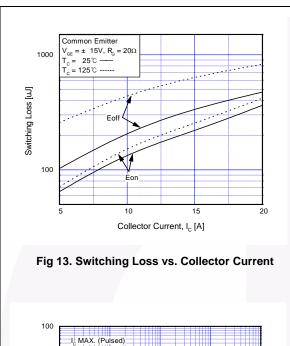


Fig 11. Turn-On Characteristics vs. Collector Current

Fig 12. Turn-Off Characteristics vs. Collector Current



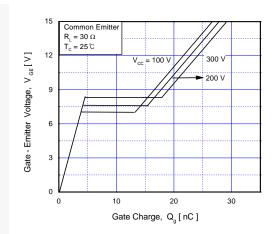
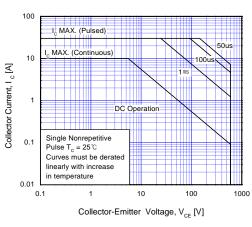


Fig 14. Gate Charge Characteristics



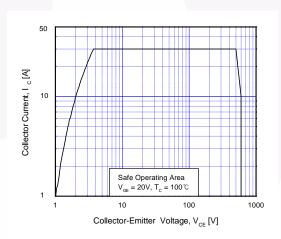


Fig 15. SOA Characteristics

Fig 16. Turn-Off SOA Characteristics

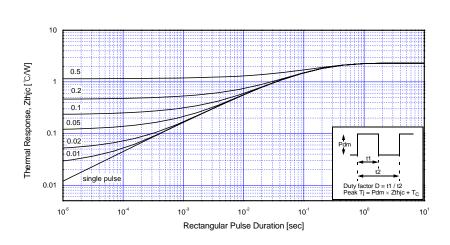
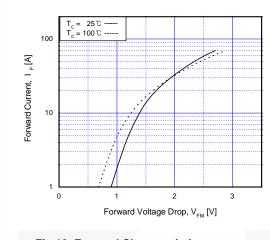


Fig 17. Transient Thermal Impedance of IGBT



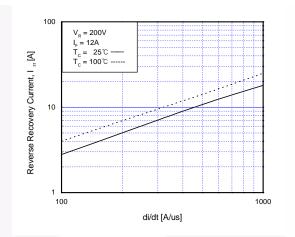
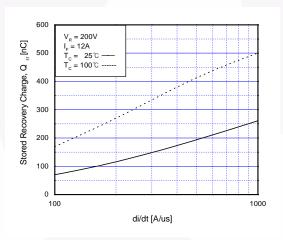


Fig 18. Forward Characteristics

Fig 19. Reverse Recovery Current



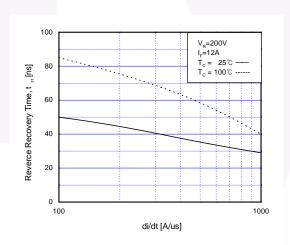


Fig 20. Stored Charge

Fig 21. Reverse Recovery Time

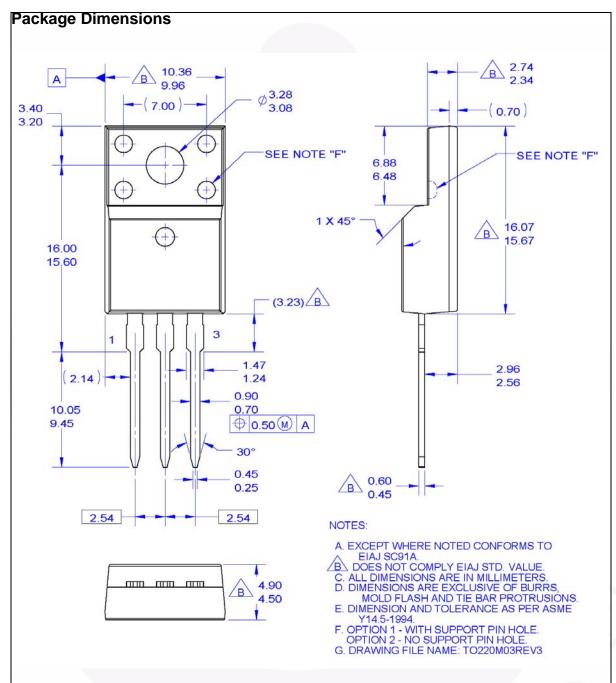


Figure 22. TO-220F 3L - TO220, MOLDED, 3LD, FULL PACK, EIAJ SC91, STRAIGHT LEAD

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